

Pb Free Plating Product

## MUR6020PT thru MUR60120PT



60.0 Ampere Heatsink Dual Common Cathode Ultra Fast Recovery Rectifiers

| Features                                                                                                                                                                                                                                                        | TO-3P(TO-3PN-SQ) Unit:inch(mm) |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------|
| ※ ThinkSemi latest&matured process FRD<br>※ Low forward voltage drop<br>※ High current capability<br>※ Low reverse leakage current<br>※ High surge current capability                                                                                           |                                |
| Application                                                                                                                                                                                                                                                     |                                |
| ※ Automotive Inverters and Solar Inverters<br>※ Car Audio Amplifiers and Sound Device Systems<br>※ Plating Power Supply, Motor Control, UPS and SMPS etc.                                                                                                       |                                |
| Mechanical Data                                                                                                                                                                                                                                                 |                                |
| ※ Case: Heatsink open metal TO-3P(TO-3PN/TO-3PB) package<br>※ Epoxy: UL 94V-0 rate flame retardant<br>※ Terminals: Solderable per MIL-STD-202 method 208<br>※ Polarity: As marked on diode body<br>※ Mounting position: Any<br>※ Weight: 6.5 gram approximately |                                |

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

| PARAMETER                                                                                                            | SYMBOL          | MUR6020PT   | MUR6030PT<br>MUR6040PT | MUR6060PT | MUR6080PT | MUR60100PT | MUR60120PT | UNIT     |
|----------------------------------------------------------------------------------------------------------------------|-----------------|-------------|------------------------|-----------|-----------|------------|------------|----------|
| Maximum Recurrent Peak Reverse Voltage                                                                               | VRRM            | 200         | 400                    | 600       | 800       | 1000       | 1200       | V        |
| Maximum RMS Voltage                                                                                                  | VRMS            | 140         | 280                    | 420       | 560       | 700        | 840        | V        |
| Maximum DC Blocking Voltage                                                                                          | VDC             | 200         | 400                    | 600       | 800       | 1000       | 1200       | V        |
| Maximum Average Forward Rectified Current TC=125℃<br>(Total Device 2x30.0A=60.0A)                                    | IF(AV)          | 60.0        |                        |           |           |            |            | A        |
| Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)(Per Diode/Per Leg) | IFSM            | 600         |                        |           |           |            |            | A        |
| Maximum Instantaneous Forward Voltage @30.0A(Per Diode/Per Leg)                                                      | VF<br>(Typical) | 0.90-1.10   | 1.10-1.40              | 1.40-1.80 | 1.40-1.80 |            |            | V        |
| Maximum DC Reverse Current @TJ=25℃<br>At Rated DC Blocking Voltage @TJ=125℃                                          | IR              | 5.0<br>500  |                        |           |           |            |            | μA<br>μA |
| Maximum Reverse Recovery Time (Note1)                                                                                | Trr             | 35-50       |                        |           | 50-75     |            |            | nS       |
| Typical Junction Capacitance (Note 2)                                                                                | CJ              | 300         |                        |           |           |            |            | pF       |
| Typical Thermal Resistance (Note 3)                                                                                  | RθJC            | 0.75        |                        |           |           |            |            | ℃/W      |
| Operating Junction and Storage Temperature Range                                                                     | TJ,TSTG         | -55 to +175 |                        |           |           |            |            | ℃        |

Note:(1)Reverse recovery test conditions IF = 0.5A, IR = 1.0A, Irr = 0.25A.

Note:(2)Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

Note:(3)Thermal Resistance junction to case.

FIG.1 - FORWARD CURRENT DERATING CURVE

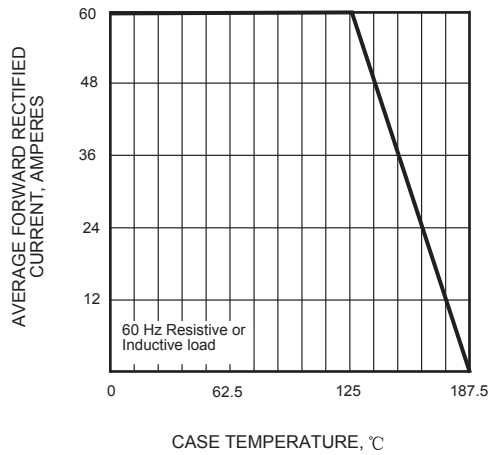


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

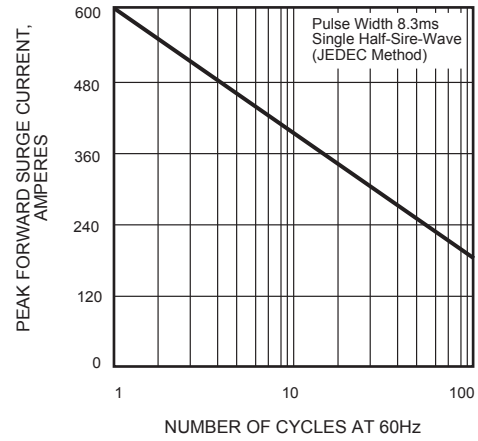


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

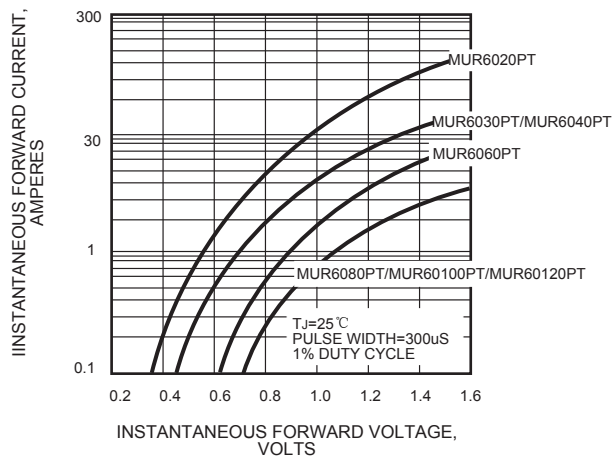


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

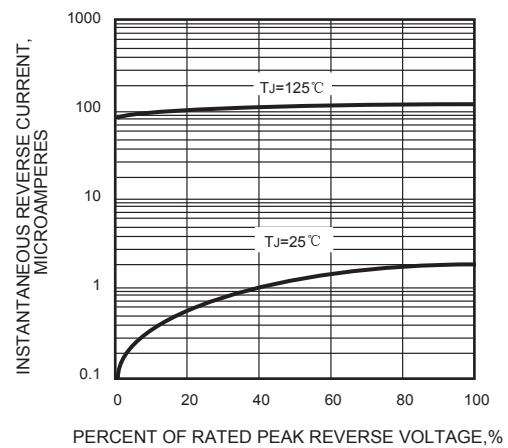


FIG.5 - TYPICAL JUNCTION CAPACITANCE

